# Old Company Name in Catalogs and Other Documents

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# **HAT1072H**

# Silicon P Channel Power MOS FET Power Switching

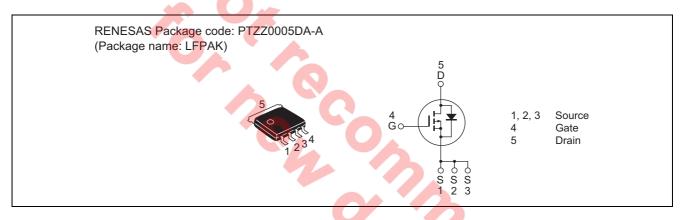
REJ03G1155-0700 (Previous: ADE-208-1534E)

Rev.7.00 Sep 07, 2005

#### **Features**

- Capable of –4.5 V gate drive
- · Low drive current
- High density mounting
- Low on-resistance  $R_{DS (on)} = 3.6 \text{ m}\Omega \text{ typ (at } V_{GS} = -10 \text{ V)}$

#### **Outline**



5/0.70

# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	-30	V
Gate to source voltage	V <sub>GSS</sub>	-20 / +10	V
Drain current	I <sub>D</sub>	-40	Α
Drain peak current	I <sub>D (pulse)</sub> Note 1	-160	Α
Body-drain diode reverse drain current	I <sub>DR</sub>	-40	Α
Channel dissipation	Pch Note 2	30	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2.  $Tc = 25^{\circ}C$ 

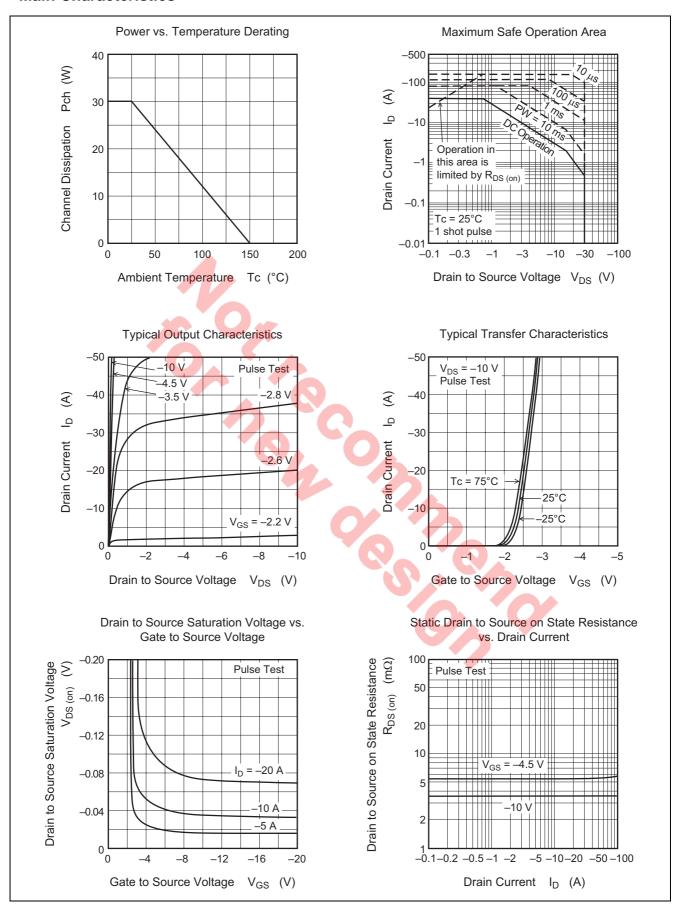
## **Electrical Characteristics**

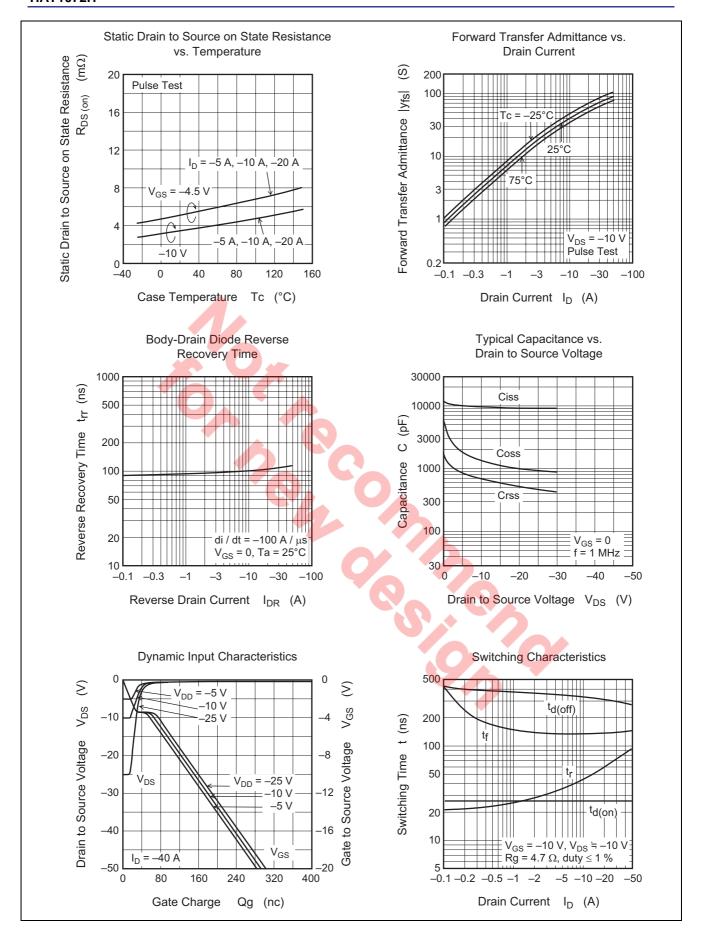
 $(Ta = 25^{\circ}C)$ 

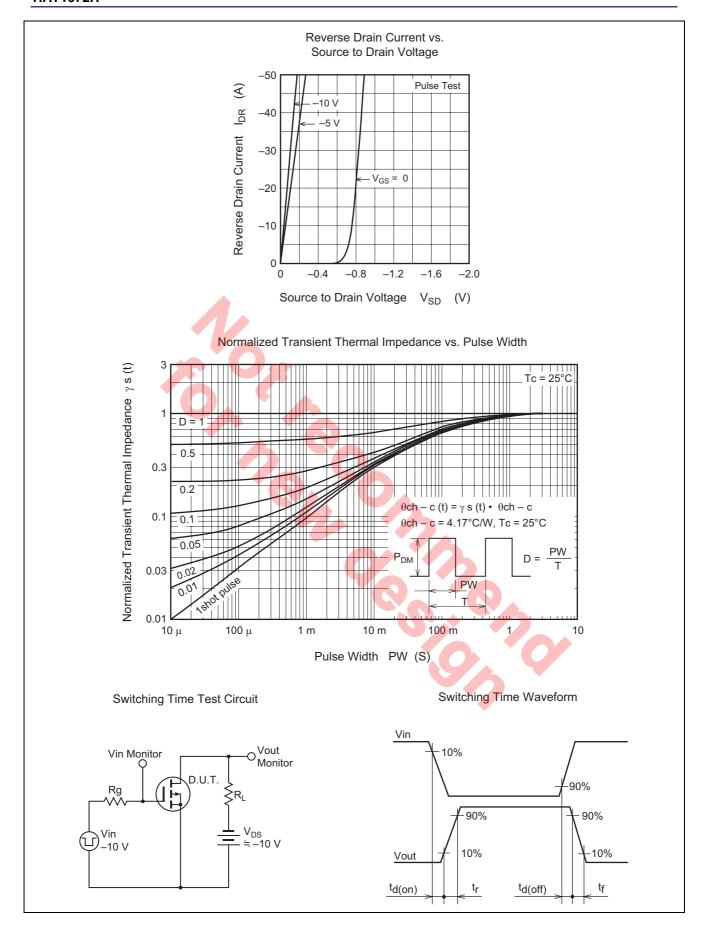
		1			ı	(14 - 25 %)
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	-30	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = -20, +10 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	-0.5	_	-2.0	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Static drain to source on state	R <sub>DS (on)</sub>		3.6	4.5	mΩ	$I_D = -20 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 3}}$
resistance	R <sub>DS (on)</sub>	Y	5.3	7.7	mΩ	$I_D = -20 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y <sub>fs</sub>	36	60	_	S	$I_D = -20 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 3}}$
Input capacitance	Ciss	_	9500	_	pF	V <sub>DS</sub> = -10 V
Output capacitance	Coss	_	1300	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss		700		pF	f = 1 MHz
Total gate charge	Qg	_	155		nC	$V_{DD} = -10 \text{ V}$
Gate to source charge	Qgs	_	28	_	nC	$V_{GS} = -10 \text{ V}$
Gate to drain charge	Qgd	_	26	_	nC	$I_D = -40 \text{ A}$
Turn-on delay time	t <sub>d (on)</sub>	_	28	_	ns	$V_{GS} = -10 \text{ V}, I_D = -20 \text{ A},$
Rise time	t <sub>r</sub>	_	60		ns	V <sub>DD</sub> ≅ -10 V
Turn-off delay time	t <sub>d (off)</sub>	_	305		ns	$R_L = 0.5 \Omega$
Fall time	t <sub>f</sub>	_	140	-	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	$V_{DF}$	_	0.87	1.14	V	$I_F = -40 \text{ A}, V_{GS} = 0^{\text{Note } 3}$
Body-drain diode reverse recovery	t <sub>rr</sub>	_	110		ns	$I_F = -40 \text{ A}, V_{GS} = 0$
time						di <sub>F</sub> /dt = 100 A/μs

Note: 3. Pulse test

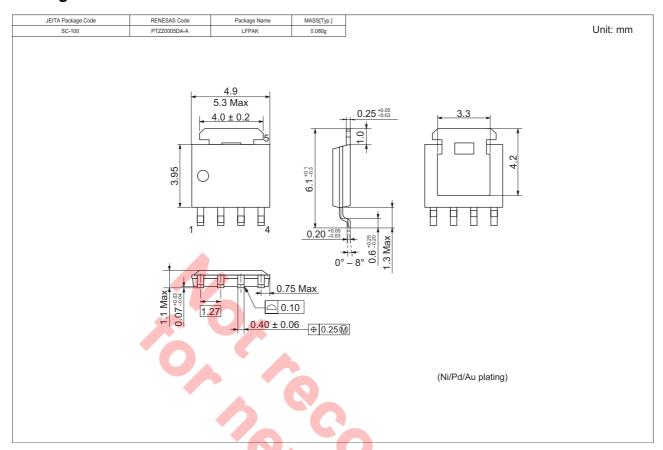
#### **Main Characteristics**







### **Package Dimensions**



# **Ordering Information**

Part Name	Quantity	Shipping Container	
HAT1072H-EL-E	2500 pcs	Taping	

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